



SOLID STATE DEVICES, INC.

14830 Valley View Blvd * La Mirada, Ca 90638

Phone: (562) 404-7855 * Fax: (562) 404-1773

ssdi@ssdi-power.com * www.ssdi-power.com

Designer's Data Sheet

FEATURES:

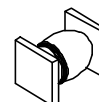
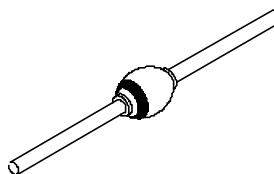
- Ultra Fast Recovery: 70 nsec maximum.
- PIV to 2400 Volts.
- Low Reverse Leakage Current.
- Hermetically Sealed.
- Low Thermal Resistance
- TX, TXV, and Space Level Screening Available
- Fast Recovery Available. Contact Factory.
- Single Junction Construction.
- Replaces 1N6512 and 1N6513 in many applications.

**SDR2UF1.8 and SMS
SDR2UF2.0 and SMS**

**2 AMP
1800 - 2000 VOLTS
70 nsec
ULTRA FAST RECOVERY
RECTIFIER**

AXIAL

SURFACE MOUNT
(SMS)



Maximum Ratings		SYMBOL	VALUE	UNITS
Reverse Voltage	SDR2UF1.8 & SMS SDR2UF2.0 & SMS	V_{RRM} V_{RWM} V_R	1800 2000	Volts
Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, T_L or $T_E = 55^\circ\text{C}$)		I_o	2	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on I_o , allow junction to reach equilibrium between pulses, $T_A = 25^\circ\text{C}$)		I_{FSM}	50	Amps
Temperature Range	Operating Storage	T_{OP} T_{STG}	-65 TO +175 -65 TO +200	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Lead, $L = .125"$ (Axial Lead) Junction to End Tab (Surface Mount)		R_{2JL} R_{2JE}	6 4	$^\circ\text{C/W}$

NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RC0063B

SDR2UF1.8 and SMS SDR2UF2.0 and SMS



SOLID STATE DEVICES, INC.

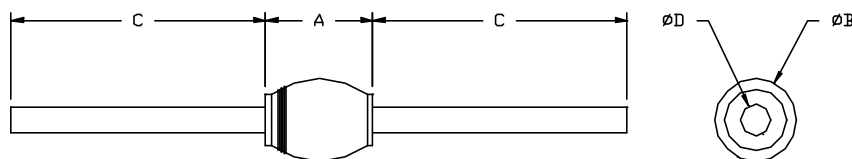
14830 Valley View Blvd * La Mirada, Ca 90638

Phone: (562) 404-7855 * Fax: (562) 404-1773

ssdi@ssdi-power.com * www.ssdi-power.com

Electrical Characteristics		SYMBOL	MIN	MAX	UNITS
Breakdown Voltage ($I_R = 50 : A$, $T_A = 25^\circ C$, 300 : s min Pulse)	SDR2UF1.8 & SMS	BV_R	--	1800	V
	SDR2UF2.0 & SMS		--	2000	
Instantaneous Forward Voltage Drop ($T_A = 25^\circ C$, 300 - 500 : s Pulse)	$I_F = 1A$	V_{F1}	--	3.60	V_{DC}
	$I_F = 2A$	V_{F2}	--	4.20	
Instantaneous Forward Voltage Drop ($T_A = -55^\circ C$, 300 - 500 : s Pulse)	$I_F = 1A$	V_{F3}	--	3.80	V_{DC}
	$I_F = 2A$	V_{F4}	--	4.60	
Reverse Leakage Current ($V_R = 85\%$ Rated V_R , $T_A = 25^\circ C$, 300 : s min Pulse)		I_{R1}	--	1.5	: A
Reverse Leakage Current ($V_R = 85\%$ Rated V_R , $T_A = 100^\circ C$, 300 : s min Pulse)		I_{R2}	--	200	: A
Junction Capacitance ($V_R = 50V$, $f = 1$ MHz, $T_A = 25^\circ C$)		C_J	--	20	pF
Reverse Recovery Time ($I_F = 500$ mA, $I_R = 1$ A, $I_{RR} = 250$ mA, $T_A = 25^\circ C$)		t_{RR}	--	70	nsec

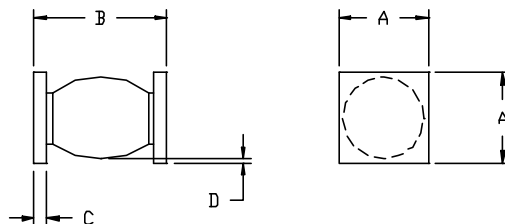
CASE OUTLINE: AXIAL LEAD



DIMENSIONS

DIM	MIN.	MAX.
A	0.240	0.270"
B	--	0.170"
C	1.00"	--
D	.045"	.051"

CASE OUTLINE: SMS



DIMENSIONS

DIM	MIN.	MAX.
A	0.170"	0.180"
B	0.290"	0.330"
C	0.020"	0.030"
D	0.002"	--

NOTES:

Consult manufacturing for operating curves.